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AD-A199 781

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Contract N00014-85-0177

R & T Code 431a003-4

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Technical Report No. 9

GROWTH AND CHARACTERIZATION OF NICKEL-DOPED ZnS SINGLE CRYSTALS

by

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Prepared for Publication in

Materials Research Bulletin

September 26, 1988

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REPORT DOCUMENTATION PAGE

1a. REPORT SECURITY CLASSIFICATION UNCLASSIFIED		1b. RESTRICTIVE MARKINGS	
2a. SECURITY CLASSIFICATION AUTHORITY		3. DISTRIBUTION / AVAILABILITY OF REPORT APPROVED FOR PUBLIC RELEASE DISTRIBUTION UNLIMITED	
2b. DECLASSIFICATION / DOWNGRADING SCHEDULE			
4 PERFORMING ORGANIZATION REPORT NUMBER(S) #9		5. MONITORING ORGANIZATION REPORT NUMBER(S) NO0014-85-0177	
6a. NAME OF PERFORMING ORGANIZATION BROWN UNIVERSITY AARON WOLD	6b. OFFICE SYMBOL (If applicable)	7a. NAME OF MONITORING ORGANIZATION OFFICE OF NAVAL RESEARCH DR. R. SCHWARTZ	
6c. ADDRESS (City, State, and ZIP Code) DEPARTMENT OF CHEMISTRY PROVIDENCE, RI 02912		7b. ADDRESS (City, State, and ZIP Code) CODE 3854 NAVAL WEAPONS CENTER CHINA LAKE, CA 93555	
8a. NAME OF FUNDING/SPONSORING ORGANIZATION	8b. OFFICE SYMBOL (If applicable)	9. PROCUREMENT INSTRUMENT IDENTIFICATION NUMBER	
8c. ADDRESS (City, State, and ZIP Code)		10. SOURCE OF FUNDING NUMBERS	
		PROGRAM ELEMENT NO.	PROJECT NO.
		TASK NO.	WORK UNIT NO.
11. TITLE (Include Security Classification) GROWTH AND CHARACTERIZATION OF NICKEL-DOPED ZnS SINGLE CRYSTALS			
12. PERSONAL AUTHOR(S) P. Wu, R. Kershaw, K. Dwight and A. Wold			
13a. TYPE OF REPORT Technical	13b. TIME COVERED FROM _____ TO _____	14. DATE OF REPORT (Year, Month, Day) September 26, 1988	15. PAGE COUNT 5
16. SUPPLEMENTARY NOTATION SUBMITTED TO MATERIALS RESEARCH BULLETIN			
17. COSATI CODES		18. SUBJECT TERMS (Continue on reverse if necessary and identify by block number)	
FIELD	GROUP	SUB-GROUP	
19. ABSTRACT (Continue on reverse if necessary and identify by block number) Crystals of zinc sulfide containing up to 3 atomic percent of nickel were grown by chemical vapor transport using iodine as the transport agent. It was found that these crystals had the same long-wavelength IR transmission characteristics as pure ZnS. Furthermore, the addition of small amounts of nickel significantly increased the hardness of ZnS. These materials may be useful for the development of IR windows in the 8-12 μm range.			
20. DISTRIBUTION/AVAILABILITY OF ABSTRACT <input type="checkbox"/> UNCLASSIFIED/UNLIMITED <input type="checkbox"/> SAME AS RPT <input type="checkbox"/> DTIC USERS		21. ABSTRACT SECURITY CLASSIFICATION	
22a. NAME OF RESPONSIBLE INDIVIDUAL		22b. TELEPHONE (Include Area Code)	22c. OFFICE SYMBOL

D. S. TR. BUCHAN LIST

GROWTH AND CHARACTERIZATION OF NICKEL-DOPED ZnS SINGLE CRYSTALS

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ABSTRACT

Crystals of zinc sulfide containing up to 5 atomic percent of nickel were grown by chemical vapor transport using iodine as the transport agent. It was found that these crystals had the same long-wavelength IR transmission characteristics as pure ZnS. Furthermore, the addition of small amounts of nickel significantly increased the hardness of ZnS. These materials may be useful for the development of IR windows in the 8-12 μm range.

MATERIALS INDEX: Zinc sulfide, Nickel

Introduction

ZnS is used as an IR window material because of its wide transmission range in the infrared. However, ZnS is soft, which limits its suitability for some applications. It was anticipated in this study that the hardness of ZnS might be improved by the introduction of transition metals, such as nickel, into its structure.

Little work has been reported on the system $\text{Ni}_x\text{Zn}_{1-x}\text{S}$, because Ni(II)(3d⁸) prefers octahedral sites and is therefore difficult to introduce into the tetrahedral ZnS structure. Czamanske and Goff (1) reported that the solubility of NiS in ZnS at 755°C was only 1.16 mole percent. Some recent spectroscopic studies (2,3) have been carried out on zinc sulfide samples doped with Ni(II). However, there has been no report on the IR transmission, magnetic properties, hardness and stability of nickel doped zinc sulfide crystals. It is the purpose of this study to investigate the properties of such materials and compare the results with those obtained for pure ZnS.

Experimental

Single Crystal Growth

Single crystals of ZnS and $\text{Ni}_x\text{Zn}_{1-x}\text{S}$, where $x = 0.05$, have been grown by chemical vapor transport using iodine as the transport agent. The zinc metal

(Gallard and Schlesinger 99.9995%) was prereduced in an Ar/H₂ (85/15) atmosphere at 200°C for 3 hours. Nickel metal (Gallard and Schlesinger) was prereduced in a Ar/H₂ atmosphere at 800°C for 12 hours. Sulfur (Gallard and Schlesinger 99.999%) was sublimed prior to use.

For ZnS crystals, stoichiometric weights of zinc and sulfur were introduced into silica tubes which were then evacuated to 10⁻⁵ torr, and 5mg/cc of iodine were added. The tubes were sealed off and enclosed in a tightly wound Kanthal coil (to even out temperature gradients) and the whole assembly was placed in a three-zone furnace. The crystal growth temperature program consisted of setting the furnace to back transport mode for one day (growth zone at 1000°C and charge zone at 800°C), equilibrating the furnace to the maximum reaction temperature for three hours, and finally, cooling the central zone at 1°C/hr to the growth temperature. Optimum crystal growth occurred when the charge zone was maintained at 950°C and the growth zone at 925°C. The transport process was carried out for a week, and the typical crystal size was 5x3x3mm. For the growth of nickel doped ZnS crystals, stoichiometric weights of metals and sulfur with various nickel to zinc ratios were introduced into a silica tube and evacuated. The growth of crystals was achieved by the above-described transport process. The real compositions of the crystals grown were determined by magnetic measurements.

Characterization

X-ray powder diffraction patterns of ground single crystals were obtained using a Philips diffractometer and monochromated high intensity CuK_{α1} radiation ($\lambda = 1.5405\text{\AA}$). For qualitative phase identification, diffraction patterns were taken over the range $12^\circ < 2\theta < 80^\circ$ with a scan rate of $1^\circ 2\theta/\text{min}$, while cell parameters were determined from scans taken at $0.25^\circ 2\theta/\text{min}$. Precise lattice parameters were obtained from these reflections using a least-squares refinement program which corrects for the systematic errors of the diffractometer.

Optical measurements on polished single-crystal slices were performed at room temperature on a Perkin-Elmer 580 single-beam scanning infrared spectrophotometer. The measurements were performed in the transmission mode over the range 2.5 μm - 25 μm . Transmission through the sample was normalized to the signal obtained in the absence of sample.

The microhardness measurements (Knoop indenter) were made on crystals using a Kentron microhardness tester. The results were obtained using a diamond indenter with 25 gram loads.

The stability of these compounds toward oxidation was determined by heating them in a flowing oxygen stream (60cc/min) and monitoring the change in weight during the heating period. The decomposition temperature was determined as the temperature where the weight of the sample began to change. The results are summarized in Table 1.

Magnetic susceptibilities were measured from liquid nitrogen temperature to 315 K using a Faraday balance at a field strength of 10.4 kOe. Honda-Owens (field dependency) plots were also made and all magnetic susceptibility data were corrected for diamagnetism (4).

TABLE 1
Properties of $Ni_xZn_{1-x}S$

x	Phase	Cell Parameter	IR Transmission Range (μm)	Knoop Hardness	Decomposition Temperature ($^{\circ}C$)
0	Cub.ZnS	a = 5.411	2.5 - 14	158 \pm 9	520
0.03	Cub.ZnS	a = 5.409	3.5 - 14	251 \pm 36	490

Results and Discussion

Single crystals of ZnS and $Ni_0.03Zn_0.97S$ have been grown by chemical vapor transport using iodine as the transport agent. The crystals averaged 5x3x3 mm in size. Pure zinc sulfide was colorless and nickel-doped zinc sulfide was dark red in color. The exact concentration of nickel in the crystals was determined by magnetic measurements. The properties of these compounds are summarized in Table 1.

Magnetic measurements were made as functions of both field and temperature. All samples, doped with nickel, showed identical paramagnetic behavior and had no field dependency at either room temperature or at liquid nitrogen temperature. The reciprocal magnetic susceptibility is plotted versus temperature in Fig. 1 and shows Curie-Weiss behavior with a Weiss constant of -78 K. The concentration of nickel can be calculated from the slope of the experimental line, by assuming a spin-only moment (2.85) of the Ni(II) ions. It was found that crystals grown from the charge containing nickel to zinc ratios of either 10/90 or 15/85 gave identical nickel contents of 5 atomic percent. This indicated that the maximum solubility at the growth conditions used had been reached.

The crystalline structures of these compounds were determined by x-ray powder diffraction analysis. Both pure ZnS crystals and ZnS crystals containing 3% nickel have the cubic stannite structure. Cell parameters obtained from a least-squares refinement showed that there was no significant change in cell parameter when 3% nickel was substituted into zinc sulfide.

The IR transmission data summarized in Table 1 are plotted in Fig. 2. The results indicate that pure ZnS crystals transmit in the range of 2.5 μm to 14 μm . The crystals containing 3 atomic percent nickel gave the same IR transmission at the long wavelength end, but there appeared to be a cut off at 3.5 μm .

Hardness (Knoop hardness number) of these compounds and their thermal stability towards oxidation are also given in Table 1. The hardness of pure zinc sulfide is 158, which is in agreement with the previous work (5), where a value of 185 was measured with a Vickers indenter. The samples doped with only 3% nickel are significantly harder than pure zinc sulfide and gave a Knoop hardness

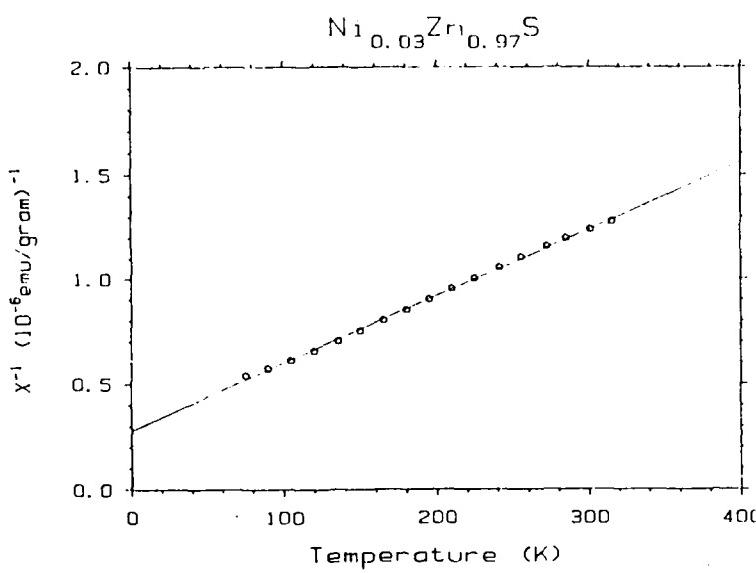


Fig. 1. Variation of magnetic susceptibility with temperature for a typical crystal of $\text{Ni}_x\text{Zn}_{1-x}\text{S}$. The composition $\text{Ni}_{0.03}\text{Zn}_{0.97}\text{S}$ was calculated from the slope of the fitted line assuming the spin-only moment of 2.83 BM per Ni(II).

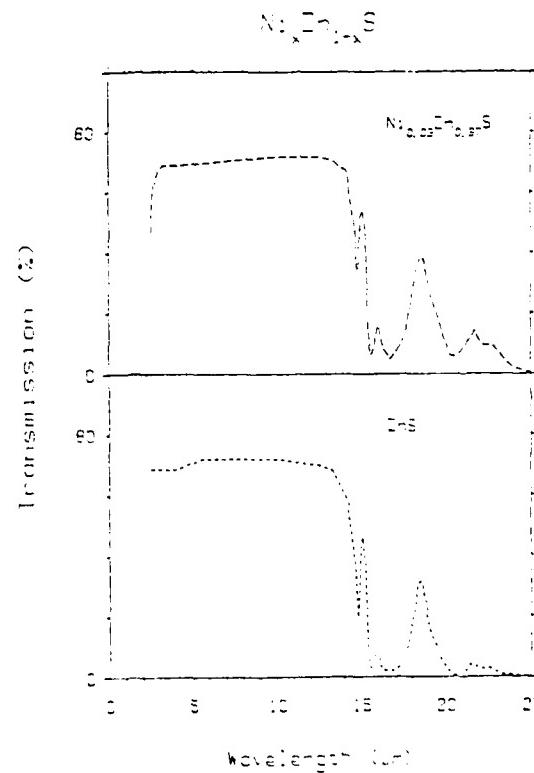


Fig. 2. The infrared spectrum of a crystal of $\text{Ni}_{0.03}\text{Zn}_{0.97}\text{S}$ compared with that of pure ZnS.

number of 251. Pure ZnS begins to decompose in flowing oxygen at 520°C and the samples containing 3 atomic percent nickel begin to decompose at 490°C.

Conclusions

It was found that, whereas ZnS doped with 3% nickel has a cut off at the short wavelength end of its IR spectrum, it provides the same IR transmission as pure ZnS at the long wavelength end. The hardness of ZnS is significantly increased by nickel doping. This should be helpful for its use as an IR window material in the range of 8 to 12 μm .

Acknowledgments

This research was supported in part by the Office of Naval Research and also by the Eastman Kodak Company, Rochester, NY.

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